

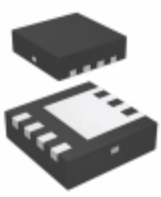







	<p>Hersteller-Teilenummer: SI7655DN-T1-GE3</p>
	<p>Hersteller / Marke: Vishay / Siliconix</p>
	<p>Teil der Beschreibung: MOSFET P-CH 20V 40A PPAK 1212</p>
	<p>Datenblätter:  SI7655DN-T1-GE3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 2330 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7655DN-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 40A PPAK 1212
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2330 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-50°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® 1212-8
Supplier Device-Gehäuse	PowerPAK® 1212-8
Verlustleistung (max)	4.8W (Ta), 57W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	40A (Tc)
Rds On (Max) @ Id, Vgs	3.6 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	1.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	225nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	6600pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)


















































SI7655DN-T1-GE3 ist neu im Original, Suche SI7655DN-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7655DN-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7655DN-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7655DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 40A PPAK 1212</p>	 <p>SI7658ADP VISHAY SI7658ADP VISHAY</p>	 <p>SI7658ADP-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 60A PPAK SO-8</p>	 <p>SI7652DP-T1-E3 VISHAY SI7652DP-T1-E3 VISHAY</p>
 <p>SI7655ADN-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 40A 1212- 8S</p>	 <p>SI7652DP-T1-GE3 VB SI7652DP-T1-GE3 VB</p>	 <p>SI7652DP-T1-E3 P/B VISHAY VISHAY QFN-8</p>	 <p>SI7655ADN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 40A 1212- 8S</p>

heiße Teile

Mehr

 SI7625DN-T1-GE3	 SI7629DN-T1	 SI7629DN-T1-GE3	 SI7629DN-T1-GE3	 SI7633DP-T1-GE3
 SI7633DP-T1-GE3	 SI7634BDP	 SI7634BDP-T1-E3	 SI7634BDP-T1-E3	 SI7634BDP-T1-GE3
 SI7634BDP-T1-GE3	 SI7634DP-T1-E3	 SI7634DP-T1-GE3	 SI7635DP	 SI7635DP-T1-GE3
 SI7635DP-T1-GE3	 SI7636DP	 SI7636DP-T1-E3	 SI7636DP-T1-E3	 SI7636DP-T1-GE3
 SI7636DP-T1-GE3	 SI7637DP-T1-E3	 SI7652DP-T1-E3	 SI7652DP-T1-GE3	 SI7655DN-T1-GE3
 SI7658ADP	 SI7658ADP-T1-E3	 SI7658ADP-T1-GE3	 SI7658ADP-T1-GE3	 SI7658DP-T1-GE3
 SI7660CJ	 SI7660DY	 SI7660DY-T1	 SI7660DY-T1-E3	 SI7661CJ
 SI7661CSA	 SI7661CSA+	 SI7668ADP-T1-E3	 SI7668ADP-T1-E3	 SI7668ADP-T1-GE3
 SI7668ADP-T1-GE3	 SI7674DP	 SI7674DP-T1-GE3	 SI7674DP-T1-GE3	 SI7682DP
 SI7682DP-T1-E3	 SI7682DP-T1-E3	 SI7682DP-T1-GE3	 SI7682DP-T1-GE3	 SI7682DY-T1-GE3

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